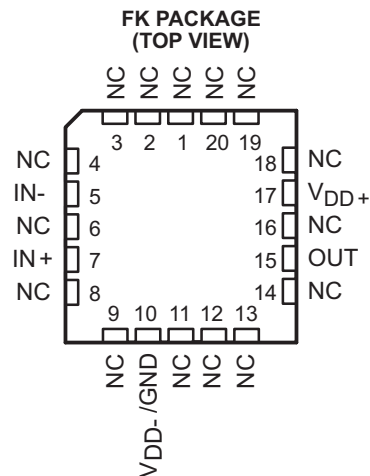


ClassV、先进 LinCMOS™ 工艺、低噪声精密运算放大器

 查询样品: [TLC2201-SP](#)

特性

- 符合 **QML-V** 标准要求的 **SMD5962-9088203V2A**
- 低输入失调电压: **400μV** (最大值)
- 在整个温度范围内提供了出色的失调电压稳定性:
0.05μV/°C (典型值)
- 轨至轨输出摆幅
- 低输入偏置电流: 在 **T_A = 25°C** 时的典型值为
1pA
- 共模输入电压范围包括负电源轨
- 技术规格针对单电源及分离电源操作全面拟订



NC - No internal connection

说明

TLC2201 是一款精密、低噪声运算放大器，运用了 TI 先进的 LinCMOS™ 制造工艺。该器件将极低噪声 JFET 放大器的噪声性能与以往仅双极型放大器可提供的直流 (dc) 精度完美地组合在了一起。Advanced LinCMOS™ 工艺采用硅栅技术来获得远远超过采用金属栅技术所能获得的随温度和时间变化的输入失调电压稳定性。此外，这项工艺技术还可实现达到或超过顶栅 JFET 和昂贵的介质隔离器件所提供的输入阻抗位准 (impedance level)。

由于兼具卓越的直流和噪声性能以及一个包括负电源轨的共模输入范围，因而使得这些器件非常适合于单电源或分离电源配置中的高阻抗、低电平信号调节应用。

器件输入和输出专为承受 -100mA 的浪涌电流而设计，而不会发生持续闭锁的现象。此外，依据 MIL-PRF-38535、Method 3015.2 所进行的测试还证实：该器件的内部 ESD 保护电路可防止在高达 2000V 的电压条件下出现功能故障；不过，在使用这些器件时应谨慎从事，因为遭受 ESD 有可能导致参数性能的下降。

TLC2201 针对完整军用温度范围内 (-40°C 至 125°C) 的运作进行了特性分析。



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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Parts, PSpice are trademarks of MicroSim Corporation.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

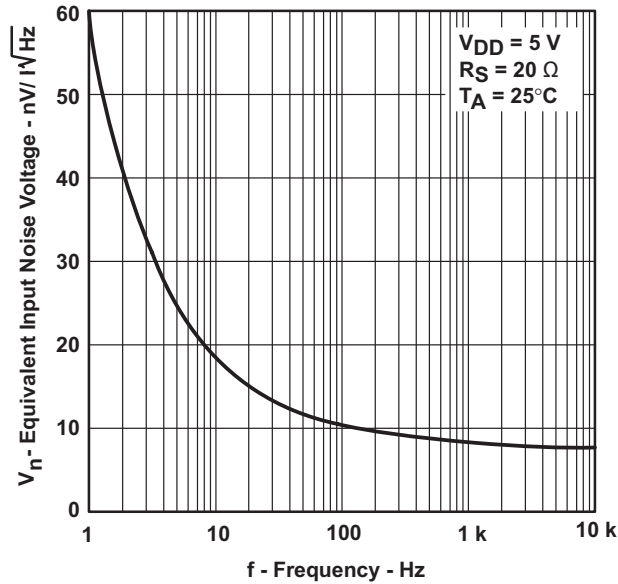
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English Data Sheet: [SLOS710](#)



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

**TYPICAL EQUIVALENT
INPUT NOISE VOLTAGE
vs
FREQUENCY**

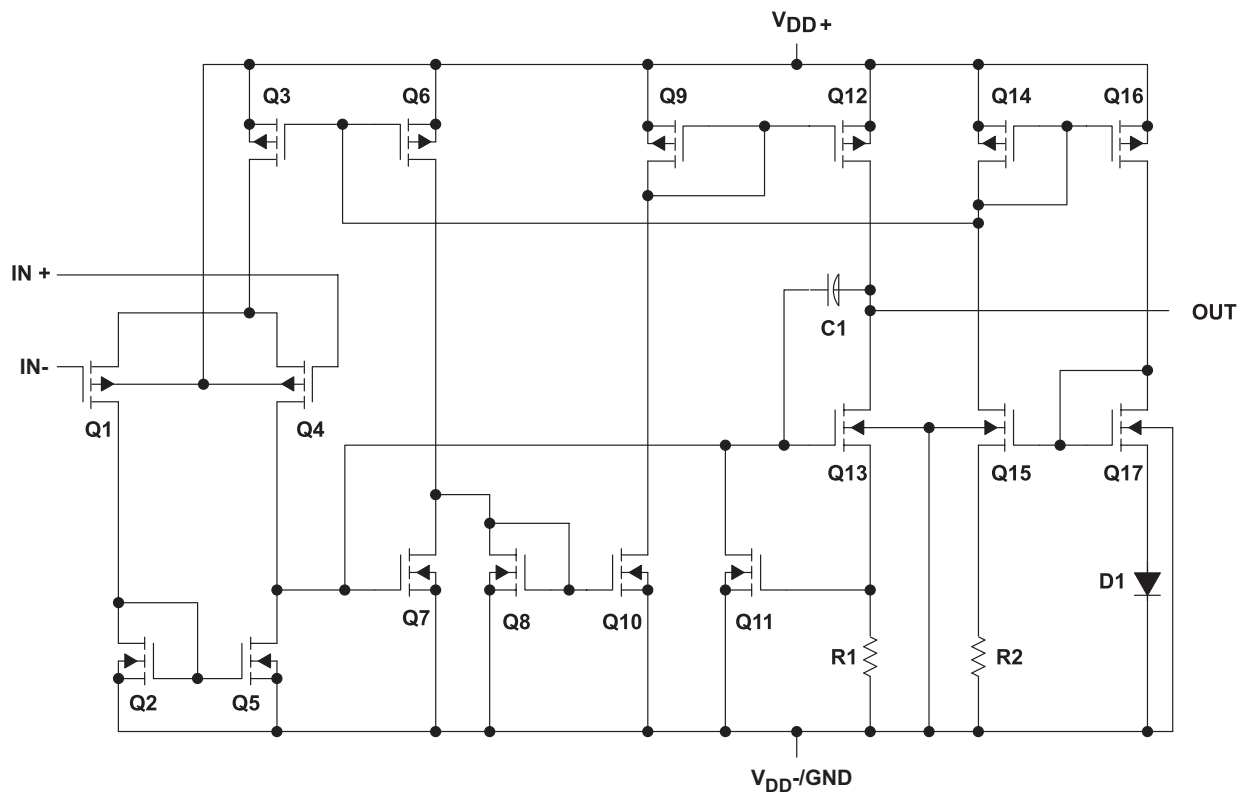


ORDERING INFORMATION⁽¹⁾

TEMPERATURE	PACKAGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-55°C to 125°C T _{case}	20-pin FK	5962-9088203V2A	5962-9088203V2A TLC2201AMFKBQMLV

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

EQUIVALENT SCHEMATIC



ACTUAL DEVICE COMPONENT COUNT	
COMPONENT	TLC2201
Transistors	17
Resistors	2
Diodes	1
Capacitors	1

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Over operating free-air temperature range (unless otherwise noted).

		VALUE	UNIT
V _{DD}	Supply voltage ⁽²⁾ , V _{DD-} to V _{DD+}	-8 to 8	V
V _{ID}	Differential input voltage ⁽³⁾	±16	V
V _I	Input voltage (any input)	±8	V
I _I	Input current (each input)	±5	mA
I _O	Output current (each output)	±50	mA
	Duration of short-circuit current at (or below) 25°C ⁽⁴⁾	Unlimited	
	Continuous total power dissipation	See Dissipation Ratings Table	
T _C	Operating case temperature	-55 to 125	°C
T _{stg}	Storage temperature	-65 to 150	°C
	Case temperature for 60 seconds	260	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values except differential voltages are with respect to the midpoint between V_{DD+} and V_{DD-}.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

THERMAL RESISTANCE FOR FK PACKAGE⁽¹⁾⁽²⁾

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
R _{θJC}	Junction-to-case thermal resistance			16	°C/W

- (1) Maximum power dissipation is a function of T_J (max), θ_{JC} and T_C. The maximum allowable power dissipation at any allowable case temperature is PD = (T_J (max) - T_C)/θ_{JC}. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (2) The package thermal impedance is calculated in accordance with MIL-STD-883.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V _{DD±}	Supply voltage	±2.3	±8	V
V _{IC}	Common-mode input voltage	V _{DD-}	V _{DD+} -2.3	V
T _C	Operating case temperature	-55	125	°C

ELECTRICAL CHARACTERISTICS

over operating free-air temperature range, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$T_A^{(1)}$	MIN	TYP	MAX	UNIT			
V_{IO}	Input offset voltage	$V_{IC} = 0,$ $R_S = 50\ \Omega$	25°C		80	200	μV			
			Full range			400				
α_{VIO}	Temperature coefficient of input offset voltage		Full range		0.5		$\mu\text{V}/^\circ\text{C}$			
	Input offset voltage long-term drift ⁽²⁾		25°C		0.001		$\mu\text{V}/\text{mo}$			
I_{IO}	Input offset current		25°C		0.5		pA			
			Full range			500				
I_{IB}	Input bias current		25°C		1		pA			
			Full range			500				
V_{ICR}	Common-mode input voltage range	$R_S = 50\ \Omega$	Full range	0 to 2.7			V			
V_{OH}	Maximum high-level output voltage	$R_L = 10\ \text{k}\Omega$	25°C	4.7	4.8		V			
			Full range	4.7						
V_{OL}	Maximum low-level output voltage		$I_O = 0$	25°C		0	50	mV		
			Full range				50			
A_{VD}	Large-signal differential voltage amplification		$V_O = 1\ \text{V to } 4\ \text{V},$ $R_L = 500\ \text{k}\Omega$	25°C	150	315		V/mV		
				Full range	75					
				25°C	$V_O = 1\ \text{V to } 4\ \text{V},$ $R_L = 10\ \text{k}\Omega$	25	55			
						Full range	10			
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0,$ $R_S = 50\ \Omega$	25°C	90	110		dB			
			Full range	85						
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)		$V_{DD} = 4.6\ \text{V to } 16\ \text{V}$	25°C	90	110		dB		
				Full range	85					
I_{DD}	Supply current			$V_O = 2.5\ \text{V},$ No load	25°C		1.1	1.5	mA	
					Full range			1.5		
SR	Slew rate at unity gain				$V_O = 0.5\ \text{V to } 2.5\ \text{V},$ $R_L = 10\ \text{k}\Omega$ $C_L = 100\ \text{pF}$	25°C	1.8	2.5		V/ μs
						Full range	1.1			
V_n	Equivalent input noise voltage	f = 10 Hz				25°C		18		nV/ $\sqrt{\text{Hz}}$
		f = 1 kHz				25°C		8		
$V_{n(pp)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz	25°C				0.5		μV	
		f = 0.1 to 10 Hz	25°C				0.7			
I_n	Equivalent input noise current		25°C			0.6		fA/ $\sqrt{\text{Hz}}$		
	Gain-bandwidth product	f = 10 kHz, $R_L = 10\ \text{k}\Omega,$ $C_L = 100\ \text{pF}$	25°C			1.8		MHz		
Φ_m	Phase margin at unity gain	$R_L = 10\ \text{k}\Omega,$ $C_L = 100\ \text{pF}$	25°C		45°					

(1) Full range is -55°C to 125°C .

(2) Typical values are based on the input offset voltage shift observable through 168 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

ELECTRICAL CHARACTERISTICS

over operating free-air temperature range, $V_{DD} = \pm 5$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$T_A^{(1)}$	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$V_{IC} = 0$, $R_S = 50 \Omega$	25°C		80	200	μV
			Full range			400	
α_{VIO}	Temperature coefficient of input offset voltage		Full range		0.5		$\mu V/^\circ C$
	Input offset voltage long-term drift ⁽²⁾		25°C		0.001		$\mu V/mo$
I_{IO}	Input offset current		25°C		0.5		μA
			Full range			500	
I_{IB}	Input bias current	25°C		1		μA	
		Full range			500		
V_{ICR}	Common-mode input voltage range	$R_S = 50 \Omega$	Full range	-5 to 2.7			V
V_{OM+}	Maximum positive peak output voltage swing	$R_L = 10 k\Omega$	25°C	4.7	4.8		V
			Full range	4.7			
V_{OM-}	Maximum negative peak output voltage swing		25°C	-4.7	-4.9		V
			Full range	-4.7			
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 4$ V, $R_L = 500 k\Omega$	25°C	400	560		V/mV
			Full range	200			
		$V_O = \pm 4$ V, $R_L = 10 k\Omega$	25°C	90	100		
			Full range	45			
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	90	115		dB
			Full range	85			
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	$V_{DD} = \pm 2.3$ V to ± 8 V	25°C	90	110		dB
			Full range	85			
I_{DD}	Supply current	$V_O = 0$ V, No load	25°C		1.1	1.5	mA
			Full range			1.5	
SR	Slew rate at unity gain	$V_O = \pm 2.3$ V, $R_L = 10 k\Omega$, $C_L = 100$ pF	25°C	2	2.7		V/ μs
			Full range	1.3			
V_n	Equivalent input noise voltage	f = 10 Hz	25°C		18		nV/ \sqrt{Hz}
		f = 1 kHz	25°C		8		
$V_{n(pp)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz	25°C		0.5		μV
		f = 0.1 to 10 Hz	25°C		0.7		
I_n	Equivalent input noise current		25°C		0.6		fA/ \sqrt{Hz}
	Gain-bandwidth product	f = 10 kHz, $R_L = 10 k\Omega$, $C_L = 100$ pF	25°C		1.9		MHz
Φ_m	Phase margin at unity gain	$R_L = 10 k\Omega$, $C_L = 100$ pF	25°C		48°		

(1) Full range is $-55^\circ C$ to $125^\circ C$.

(2) Typical values are based on the input offset voltage shift observable through 168 hours of operating life test at $T_A = 150^\circ C$ extrapolated to $T_A = 25^\circ C$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

PARAMETER MEASUREMENT INFORMATION

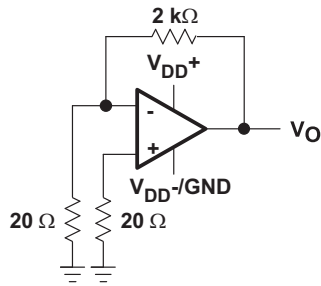
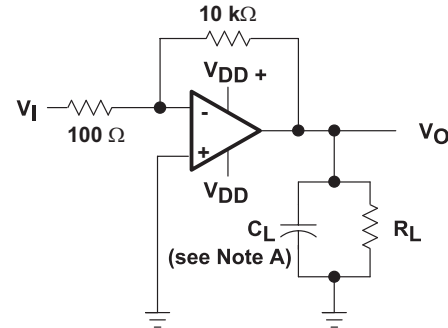
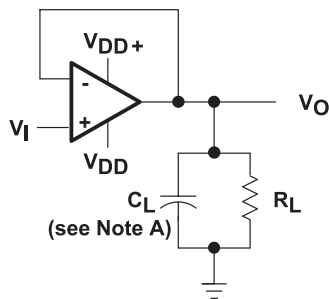


Figure 1. Noise-Voltage Test Circuit



NOTE A: C_L includes fixture capacitance.

Figure 2. Phase-Margin Test Circuit



NOTE A: C_L includes fixture capacitance.

Figure 3. Slew-Rate Test Circuit

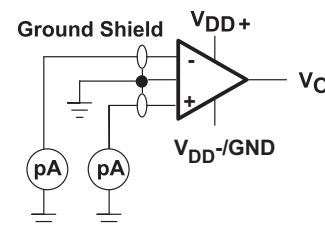


Figure 4. Input-Bias and Offset-Current Test Circuit

TYPICAL VALUES

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.

INPUT BIAS AND OFFSET CURRENT

At the picoamp bias current level of the TLC2201 accurate measurement of the bias current becomes difficult. Not only does this measurement require a picoammeter, but test socket leakages can easily exceed the actual device bias currents. To measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied but with no device in the socket. The device is then inserted in the socket, and a second test measuring both the socket leakage and the device input bias current is performed. The two measurements are then subtracted algebraically to determine the bias current of the device.

NOISE

Texas Instruments offers automated production noise testing to meet individual application requirements. Noise voltage at $f = 10$ Hz and $f = 1$ kHz is sample tested on every TLC2201. For other noise requirements, please contact the factory.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution	Figure 5
I_{IB}	Input bias current	vs Common-mode input voltage	Figure 6
		vs Free-air temperature	Figure 7
V_{OM}	Maximum peak output voltage	vs Output curre	Figure 8
		vs Free-air temperature	Figure 9
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	Figure 10
V_{OH}	High-level output voltage	vs Frequency	Figure 11
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		vs Free-air temperature	Figure 13
V_{OL}	Low-level output voltage	vs Low-level output current	Figure 14
		vs Free-air temperature	Figure 15
A_{VD}	Large-signal differential voltage amplification	vs Frequency	Figure 16
		vs Free-air temperature	Figure 17
I_{OS}	Short-circuit output current	vs Supply voltage	Figure 18
		vs Free-air temperature	Figure 19
CMRR	Common-mode rejection ratio	vs Frequency	Figure 20
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		vs Free-air temperature	Figure 22
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			Figure 24
		Large signal	Figure 25
			Figure 26
SR	Slew rate	vs Supply voltage	Figure 27
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		0.1 Hz to 10 Hz	Figure 30
	Gain-bandwidth product	vs Supply voltage	Figure 31
		vs Free-air temperature	Figure 32
Φ_m	Phase margin	vs Supply voltage	Figure 33
		vs Free-air temperature	Figure 34
	Phase shift	vs Frequency	Figure 16

TYPICAL CHARACTERISTICS

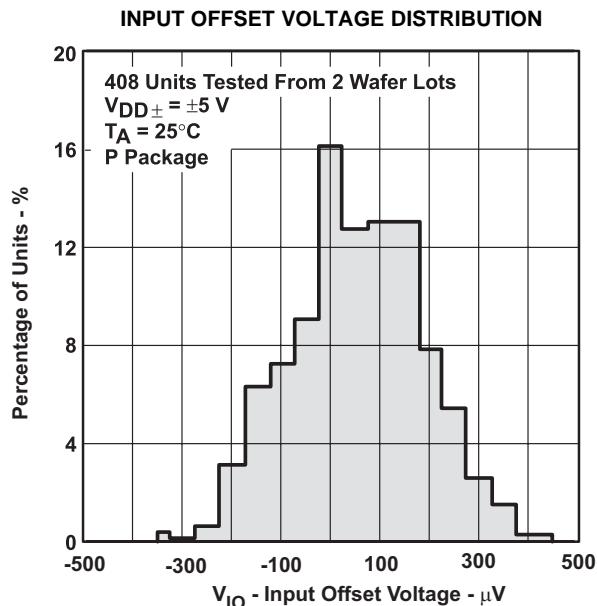


Figure 5.

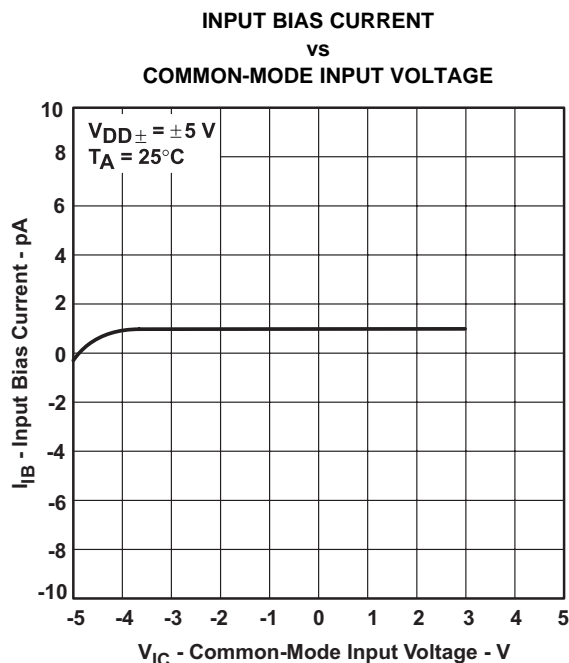


Figure 6.

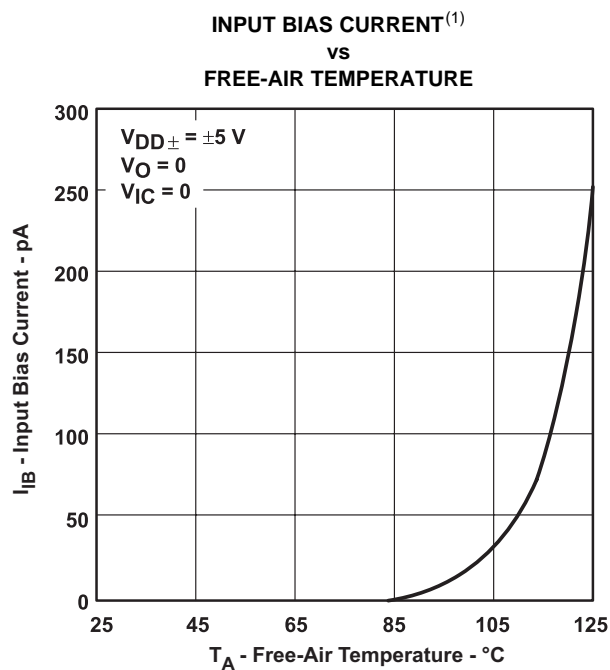


Figure 7.

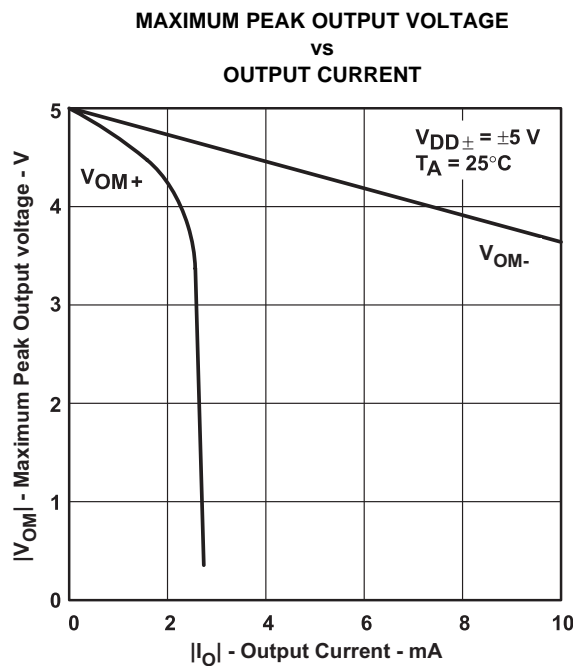


Figure 8.

(1) Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS (continued)

MAXIMUM PEAK OUTPUT VOLTAGE⁽²⁾
vs
FREE-AIR TEMPERATURE

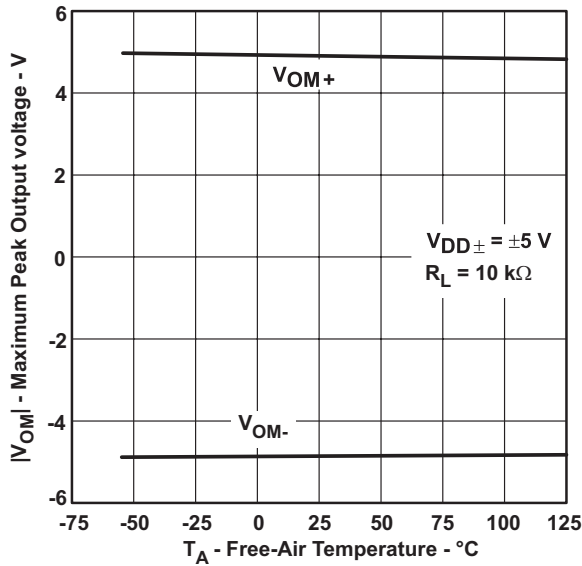


Figure 9.

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE
vs
FREQUENCY

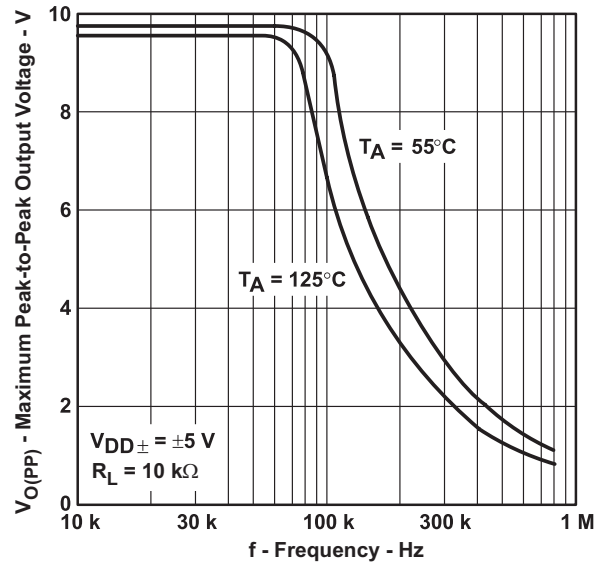


Figure 10.

HIGH-LEVEL OUTPUT VOLTAGE
vs
FREQUENCY

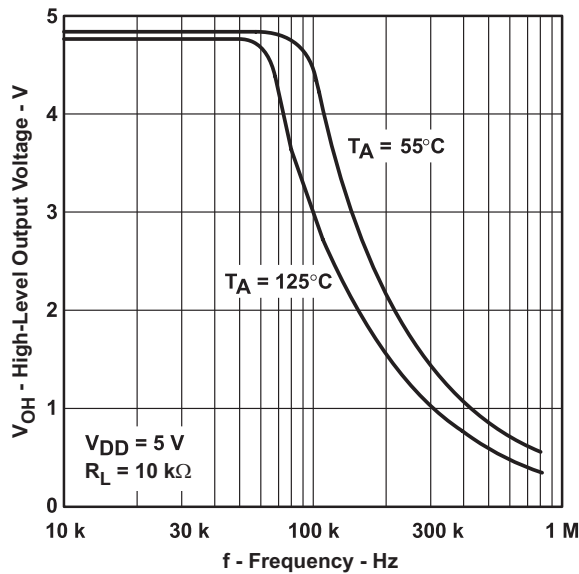


Figure 11.

HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

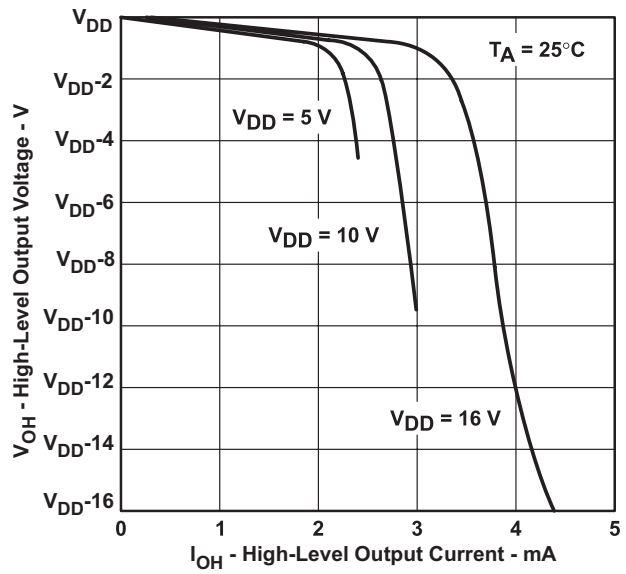


Figure 12.

(2) Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS (continued)

HIGH-LEVEL OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

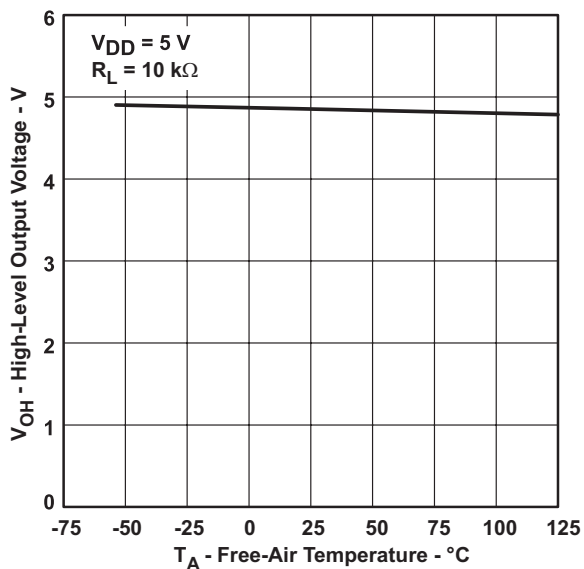


Figure 13.

LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

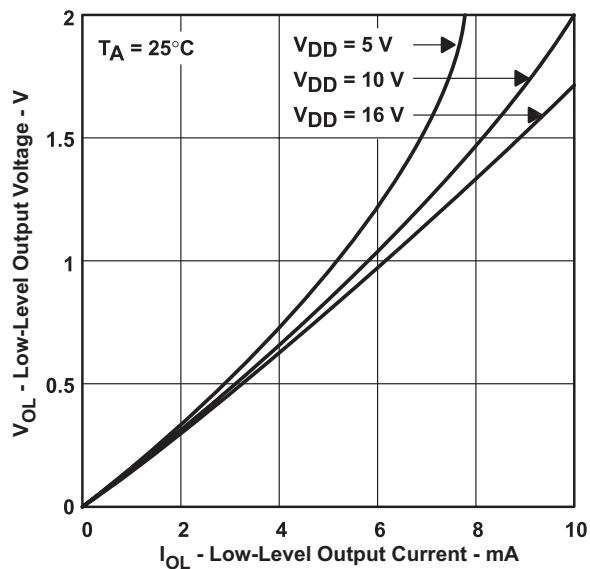


Figure 14.

LOW-LEVEL OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

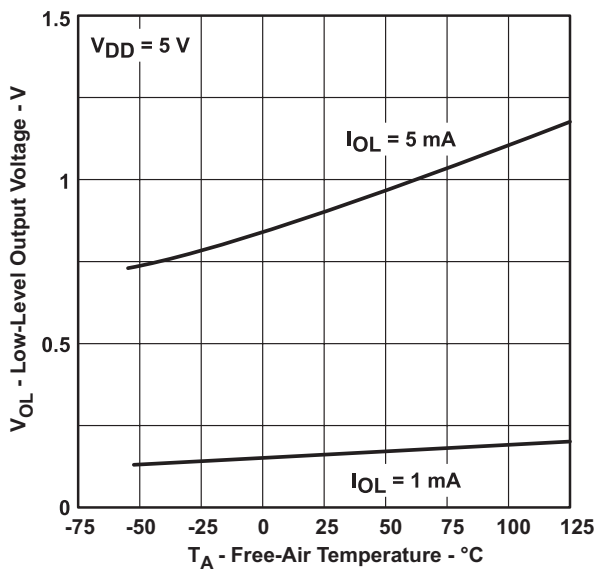


Figure 15.

LARGE-SIGNAL DIFFERENTIAL VOLTAGE
AMPLIFICATION AND PHASE SHIFT
vs
FREQUENCY

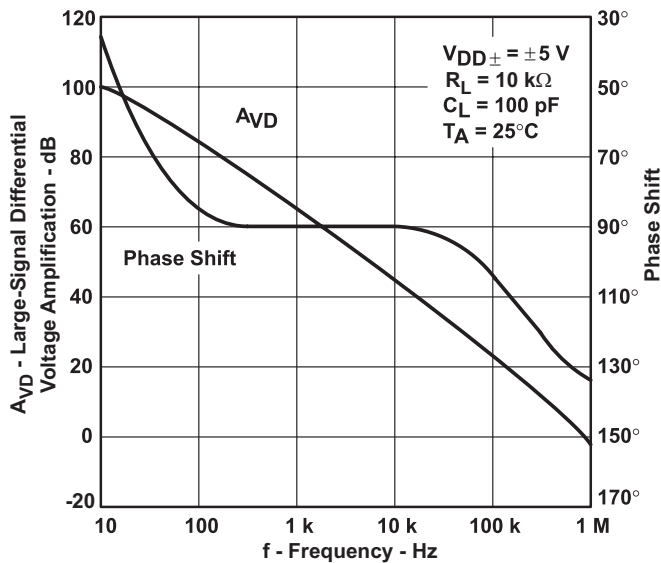


Figure 16.

TYPICAL CHARACTERISTICS (continued)

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION
vs
FREE-AIR TEMPERATURE

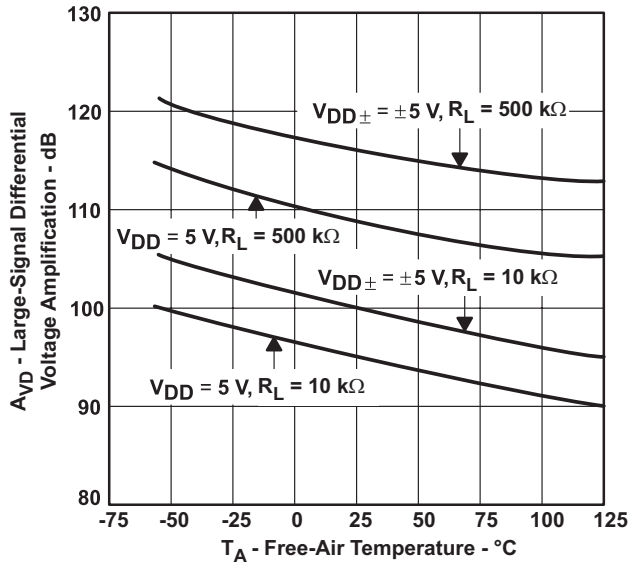


Figure 17.

SHORT-CIRCUIT OUTPUT CURRENT
vs
SUPPLY VOLTAGE

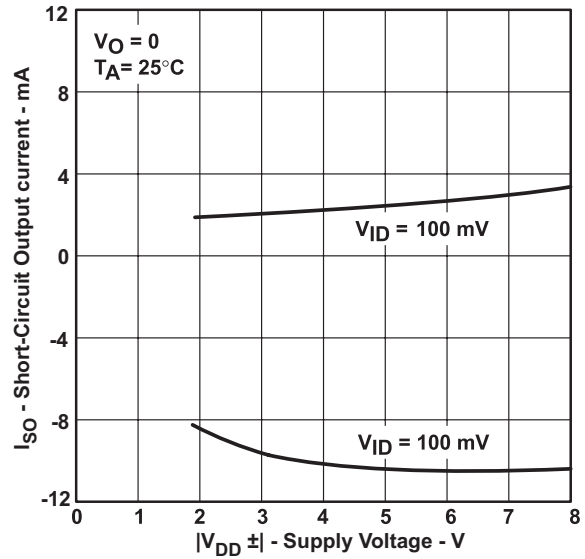


Figure 18.

SHORT-CIRCUIT OUTPUT CURRENT
vs
FREE-AIR TEMPERATURE

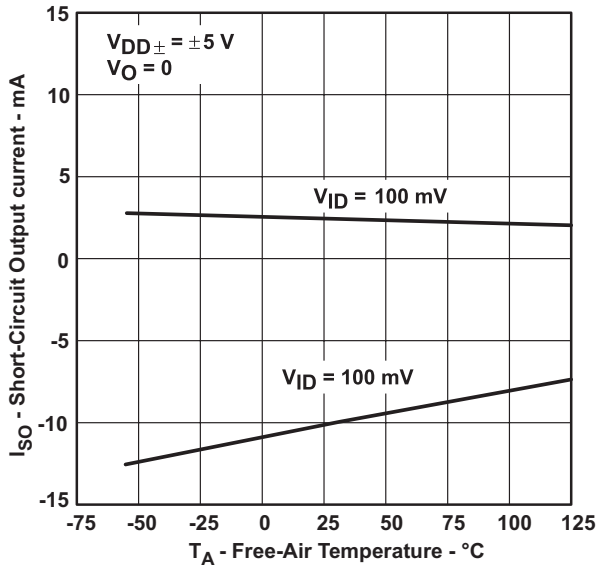


Figure 19.

COMMON-MODE REJECTION RATIO
vs
FREQUENCY

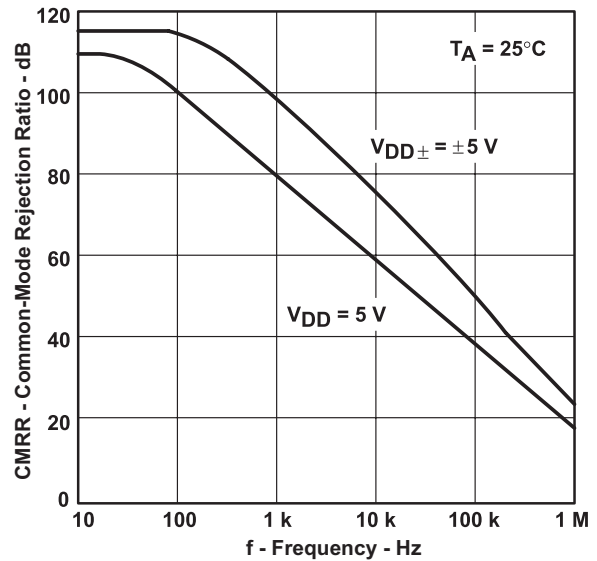


Figure 20.

TYPICAL CHARACTERISTICS (continued)

SUPPLY CURRENT
vs
SUPPLY VOLTAGE

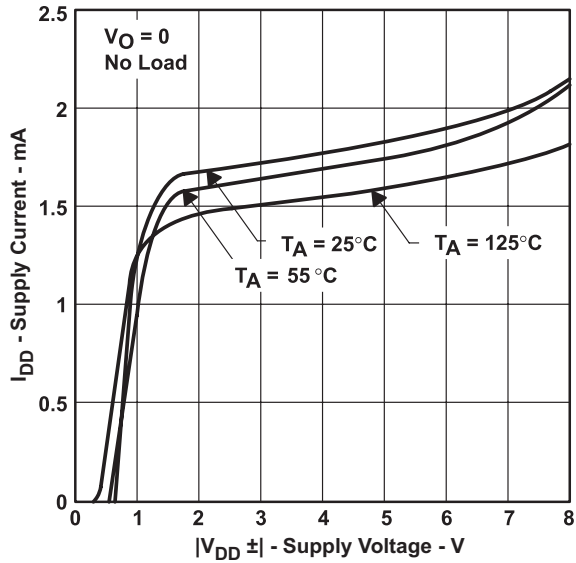


Figure 21.

SUPPLY CURRENT
vs
FREE-AIR TEMPERATURE

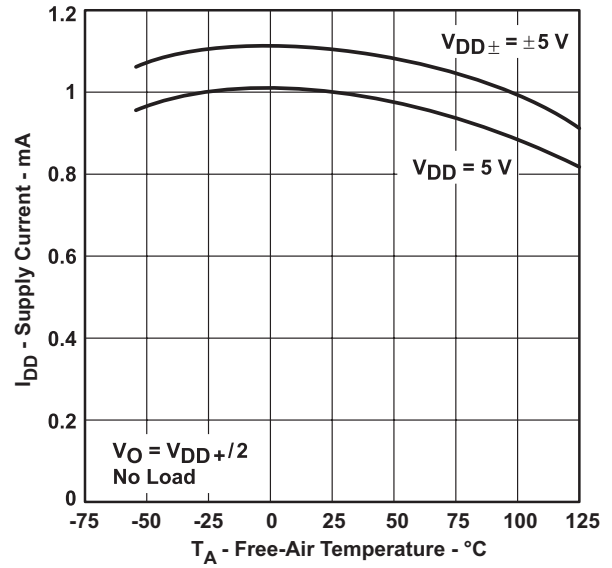


Figure 22.

VOLTAGE-FOLLOWER
SMALL-SIGNAL
PULSE RESPONSE

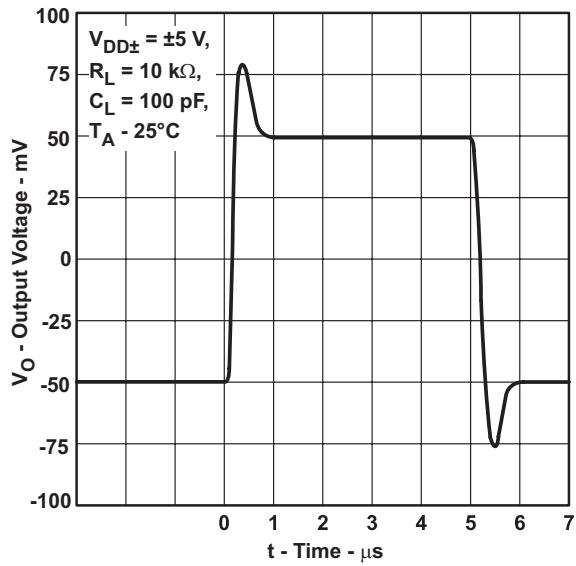


Figure 23.

VOLTAGE-FOLLOWER
SMALL-SIGNAL
PULSE RESPONSE

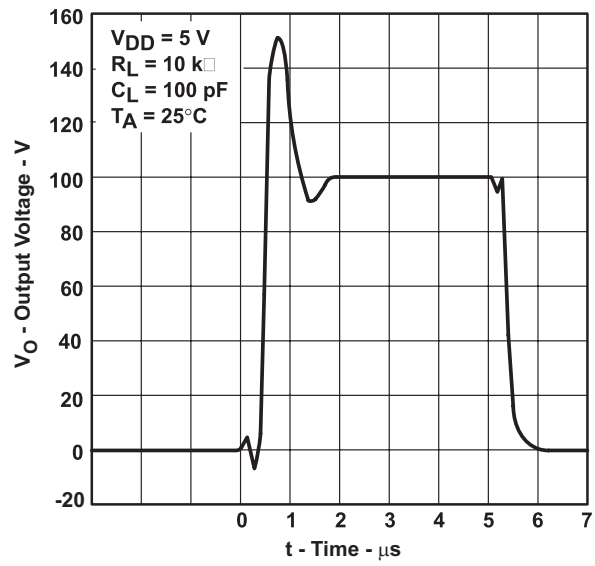


Figure 24.

TYPICAL CHARACTERISTICS (continued)

**VOLTAGE-FOLLOWER
LARGE-SIGNAL
PULSE RESPONSE**

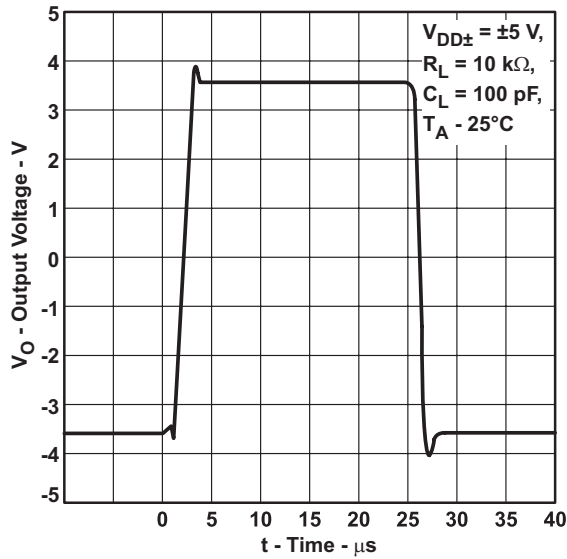


Figure 25.

**VOLTAGE-FOLLOWER
LARGE-SIGNAL
PULSE RESPONSE**

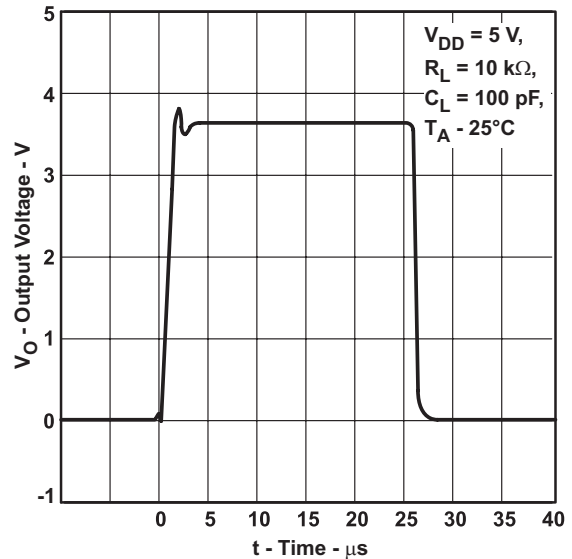


Figure 26.

**SLEW RATE
vs
SUPPLY VOLTAGE**

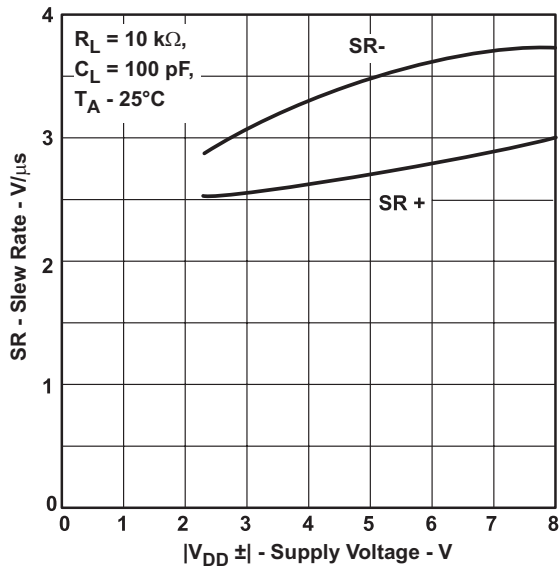


Figure 27.

**SLEW RATE
vs
FREE-AIR TEMPERATURE**

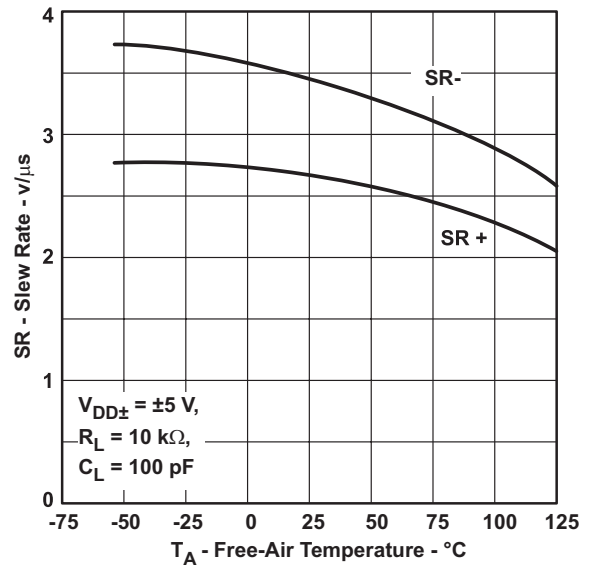


Figure 28.

TYPICAL CHARACTERISTICS (continued)

NOISE VOLTAGE
(REFERRED TO INPUT)
OVER A 10-SECOND INTERVAL

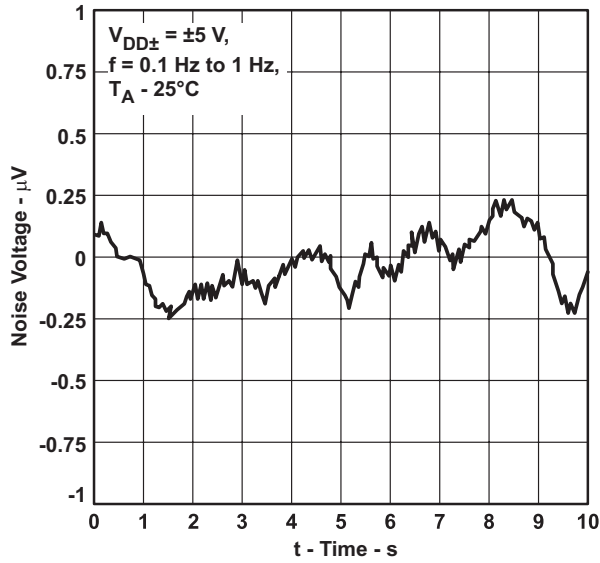


Figure 29.

NOISE VOLTAGE
(REFERRED TO INPUT)
OVER A 10-SECOND INTERVAL

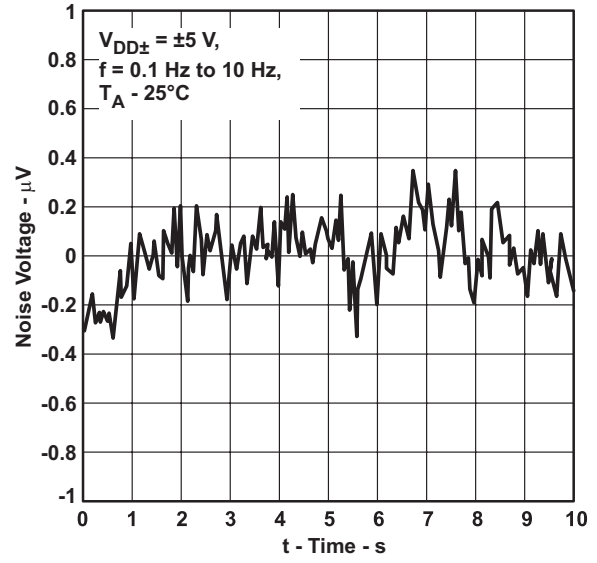


Figure 30.

GAIN-BANDWIDTH PRODUCT
vs
SUPPLY VOLTAGE

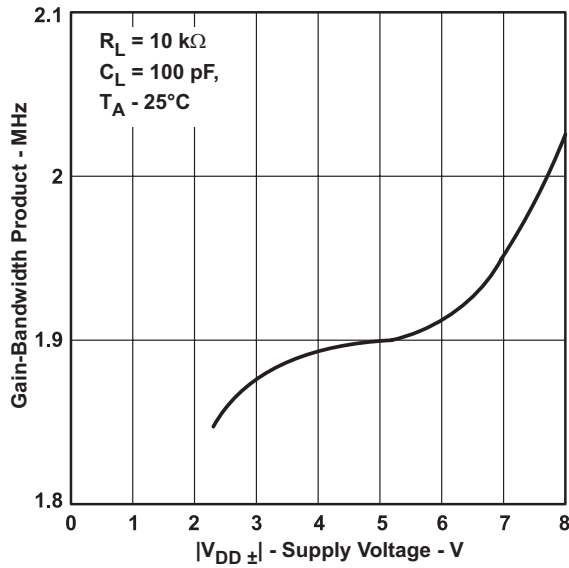


Figure 31.

GAIN-BANDWIDTH PRODUCT
vs
FREE-AIR TEMPERATURE

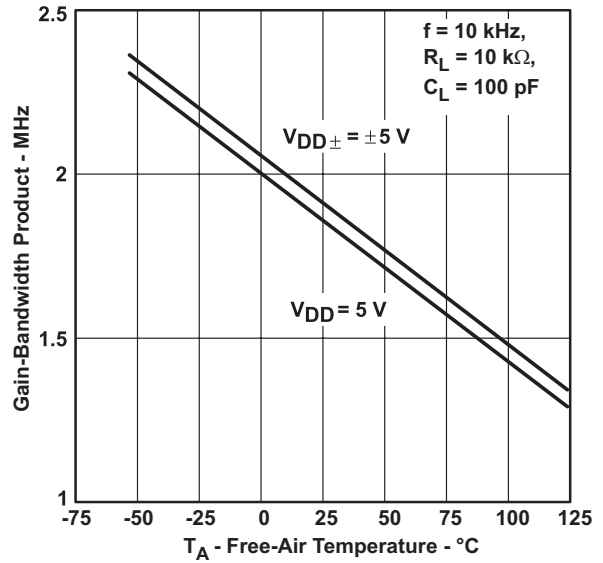
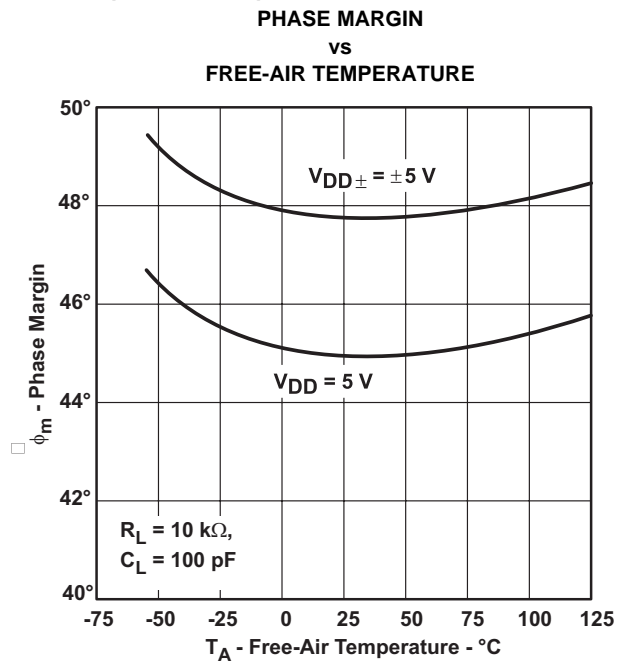
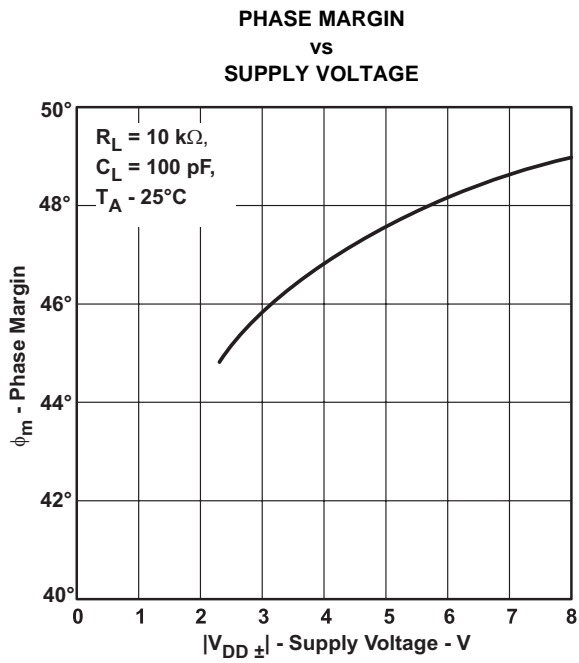


Figure 32.

TYPICAL CHARACTERISTICS (continued)



APPLICATION INFORMATION

LATCH-UP AVOIDANCE

Because CMOS devices are susceptible to latch-up due to their inherent parasitic thyristors, the TLC2201 inputs and outputs are designed to withstand -100-mA surge currents without sustaining latch-up; however, techniques reducing the chance of latch-up should be used whenever possible. Internal protection diodes should not be forward biased in normal operation. Applied input and output voltages should not exceed the supply voltage by more than 300 mV. Care should be exercised when using capacitive coupling on pulse generators. Supply transients should be shunted by the use of decoupling capacitors (0.1 μF typical) located across the supply rails as close to the device as possible.

ELECTROSTATIC DISCHARGE PROTECTION

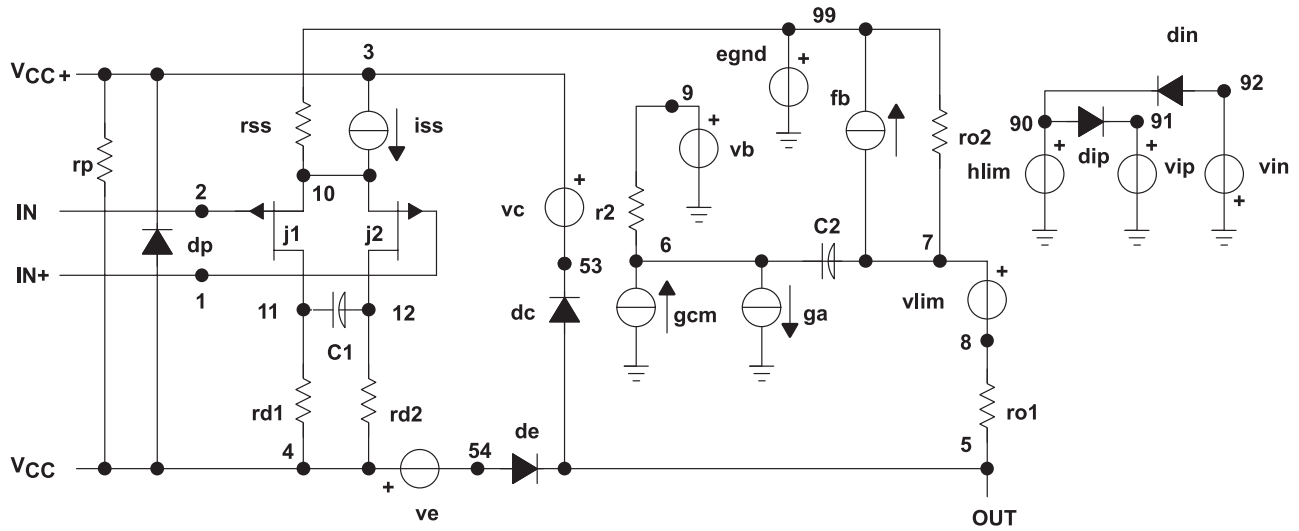
These devices use internal ESD-protection circuits that prevent functional failures at voltages at or below 2000 V. Care should be exercised in handling these devices as exposure to ESD may result in degradation of the device parametric performance.

MACROMODEL INFORMATION

Macromodel information provided was derived using Microsim Parts™, the model generation software used with Microsim PSpice™. The Boyle macromodel⁽³⁾ and subcircuit in [Figure 35](#) were generated using the TLC2201 typical electrical and operating characteristics at 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

(3) G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", IEEE Journal of Solid-State Circuits, SC-9, 353 (1974).



```

.subckt TLC220x 1 2 3 4 5
*
c1 11 12 8.51E12
c2 6 7 50.00E12
cpsr 85 86 79.6E9
dcm+ 81 82 dx
dcm 83 81 dx
dc 5 53 dx
de 54 5 dx
dlp 90 91 dx
dln 92 90 dx
dp 4 3 dx
ecmr 84 99 (2,99) 1
egnd 99 0 poly(2) (3,0) (4,0) 0 .5 .5
epsr 85 0 poly(1) (3,4) 200E6 20E6
ense 89 2 poly(1) (88,0) 100E6 1
fb 7 99 poly(6) vb vc ve vlp vln
+ vpsr 0 + 895.9E3 90E3 90E3 90E3 90E3 895E3
ga 6 0 11 12 314.2E6
gcm 0 6 10 99 1.295E9
gpsr 85 86 (85,86) 100E6
grd1 60 11 (60,11) 3.141E4
grd2 60 12 (60,12) 3.141E4
hlim 90 0 vlim 1k
hcmr 80 1 poly(2) vcm+ vcm 0 1E2 1E2
irp 3 4 965E6
iss 3 10 dc 135.0E6
iio 2 0 .5E12
i1 88 0 1E21
j1 11 89 10 jx
j2 12 80 10 jx
r2 6 9 100.0E3
rcm 84 81 1k
rn1 88 0 1500
ro1 8 5 188
ro2 7 99 187
rss 10 99 1.481E6
vad 60 4 .3v
vcm+ 82 99 2.2
vcm 83 99 4.5
vb 9 0 dc 0
vc 3 53 dc .9
ve 54 4 dc .8
vlim 7 8 dc 0
vlp 91 0 dc 2.8
vln 0 92 dc 2.8
vpsr 0 86 dc 0
.model dx d(is=800.0E18)
.model jx pjf(is=500.0E15 beta=1.462E3
+ vto=.155 kf=1E17)
.endsx
    
```

Figure 35. Boyle Macromodel and Subcircuit

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光纤网络	http://www.ti.com.cn/opticalnetwork
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电话	http://www.ti.com.cn/telecom
视频与成像	http://www.ti.com.cn/video
无线	http://www.ti.com.cn/wireless

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9088203V2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088203V2A TLC2201 AMFKBQMLV
5962-9088203V2A.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9088203V2A TLC2201 AMFKBQMLV

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF TLC2201-SP :

- Catalog : [TLC2201](#)
- Military : [TLC2201M](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

GENERIC PACKAGE VIEW

FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4229370VA\

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最后更新日期：2025 年 10 月